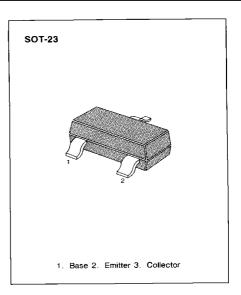


GENERAL PURPOSE TRANSISTOR

ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

Characteristic	Symbol	Rating	Unit
Collector-Base Voltage Collector-Emitter Voltage Emitter-Base Voltage Collector Current Collector Dissipation Storage Temperature	V _{CBO} V _{CEO} V _{EBO} I _C P _C Tstq	-50 -40 -5 -100 350 150	V V MA mW

[•] Refer to KST5088 for graphs



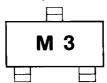
ELECTRICAL CHARACTERISTICS ($T_a = 25$ °C)

Characteristic	Symbol	Test Condition	Min	Max	Unit
Collector Cut-off Current	Ісво	$V_{CB} = -40V, i_E = 0$		- 100	nA
Emitter Cut-off Current	I _{EBO}	$V_{EB} = -5V, I_{C} = 0$		– 100	nA
DC Current Gain	h _{FE}				
KST812M3		$V_{CE} = -6V, I_{C} = -1mA$	60	120	
KST812M4			90	180	
KST812M5	1		135	270	
KST812M6			200	400	
KST812M7			300	600	
Collector-Emitter Saturation Voltage	V _{CE} (sat)	$I_{C} = -30 \text{mA}, I_{B} = -3 \text{mA}$		- 0.5	v
Base-Emitter On Voltage	V _{BE} (on)	$V_{CE} = -6V, I_{C} = -1mA$		- 0.8	V

MARKING CODE

TYPE	KST812M3	KST812M4	KST812M5	KST812M6	KST812M7
MARK	МЗ	M4	M5	М6	M7

Marking



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